SIC SCHOTTKY DIODE TYPE 2×50A

Maximum DC

Blocking

Voltage

650V

Preliminary

Features

- High surge current capable
- Zero reverse recovery current VDC
- · High bandwidth
- Temperature Independent Switching Behavior
- 650 V • **I**F(Tc<135°C) 2×50 A
- Isolation type package

Benefits

- Unipolar rectifier
- Zero switching loss
- Smaller heat sink

Operating Junction Temperature : $-55 \,^{\circ}\text{C}$ to $+175 \,^{\circ}\text{C}$

Storage Temperature : $-55 \,^{\circ}\text{C}$ to $+175 \,^{\circ}\text{C}$

- Parallel devices without thermal runaway
- Higher efficiency

Applications

- Motor drives
- Switch mode power supplies
- Ev chargers
- Solar inverters
- Power factor correction
- Diode snubber
- Automotive

Maximum Recurrent

Peak Reverse

Voltage

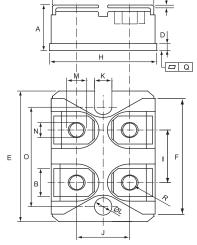
650V

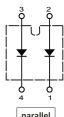
- induction heating
- Welding equipment

Maximum Ratings

Part Number

CSRI2×50-065P1B





ć	j ĝ	ģ
2	_ `	
(——-	5
	paralle	

o o o o o o o o o o o o o o o o o o o
DIMENSIONS

Maximum Rating	Symbol	Conditions	Value	Unit
Continuous forward current (per diode)	I _F	T _C =135 °C	50	
Surge non-repetitive forward current	I _{FSM}	T _C =25 °C, t _p =8.3 ms	400	
sine halfwave (per diode)	-F-SWI	T _C =150 °C, t _p =8.3 ms	250	Α
Non-repetitive peak forward current	l-	T_{C} =25 °C, t_{p} =10 μ s	1600	
(per diode)	I _{F,max}	T_{C} =150 °C, t_{p} =10 μ s	1000	
Repetitive peak reverse voltage	V_{RRM}	T _j =25 °C	650	V
Isolation voltage between All Terminals and Baseplate	V _{iso}	50/60 Hz, t=1min I _{ISOL} ≤ 1mA	2500	V
Mounting torque		To heatsink	1.3	Nm
Intoditing torque		To Assess to all		1 1 1 1 1 1

DIMENSIONS						
	INCHES		M	MM		
	MIN	MAX	MIN	MAX		
Α	0.460	0.483	11.68	12.28		
В	0.307	0.323	7.80	8.20		
С	0.030	0.033	0.75	0.85		
D	0.071	0.081	1.80	2.05		
Е	1.488	1.504	37.80	38.20		
F	1.248	1.260	31.70	32.00		
G	0.917	0.957	23.30	24.30		
Н	0.996	1.008	25.30	25.60		
1	0.579	0.602	14.70	15.30		
J	0.492	0.516	12.50	13.10		
K	0.161	0.169	4.10	4.30		
L	0.161	0.169	4.10	4.30		
М	0.181	0.197	4.60	5.00		
N	0.165	0.181	4.20	4.60		
0	1.181	1.197	30.00	30.40		
Q	-0.002	0.004	-0.05	0.10		
R	M4*8					
	-	-				

1.1

To terminal

CSRI2×50-065P1B

Electrical Characteristics, at T_i=25 °C, unless otherwise specified. (per diode)

Static Characteristics	Symbol Conditions	Conditions	Values			
		min.	typ.	max.	Unit	
DC blocking voltage	V _{DC}		650	-	-	
	V _F	I _F =50A, T _j =25 °C	-	1.50	1.70	V
Diode forward voltage		I _F =50A, T _j =175 °C	-	1.70	2.00	
	l-	V _R =650V, T _j =25 °C	-	30	60	
Reverse current	I _R	V _R =650V, T _j =175 °C	-	60	250	μΑ

AC Characteristics (per diode)

Static Characteristics	Symbol Co	Conditions	Values			
		Conditions	min.	typ.	max.	Unit
Total capacitive charge	Q _{rr}	V _R =400V, T _j =25 °C	-	89.35	-	nC
Total capacitance		V _R =0V, f=1 MHz T _j =25 °C	-	1700	-	pF
	С	V _R =200V, f=1 MHz T _j =25 °C	-	270	-	
		V _R =400V, f=1 MHz T _j =25 °C	-	246	-	

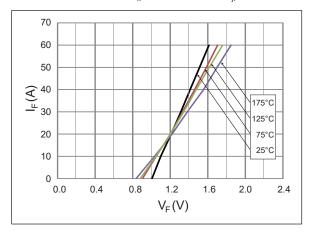
Thermal Characteristics (per diode)

Static Characteristics	Symbol	Values		
Static Characteristics	Syllibol	typ.	Unit	
Thermal resistance from junction to case	$R_{ heta JC}$	0.28	°C/W	

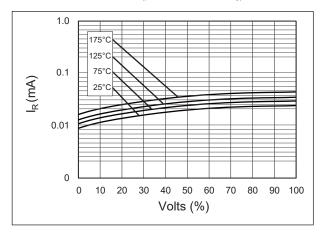
CSRI2×50-065P1B

Typical Performance

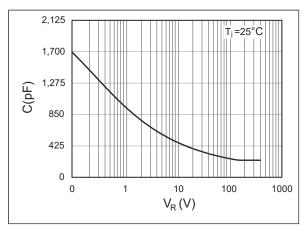
Forward Characteristics (parameterized on T_i)



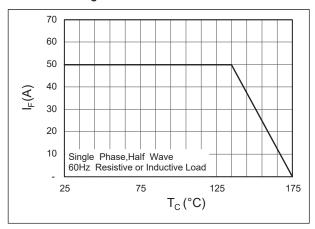
Reverse Characteristics (parameterized on Tj)



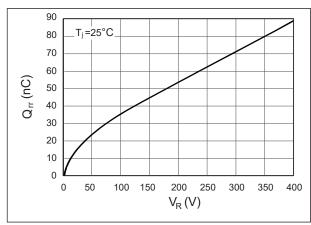
Capacitance



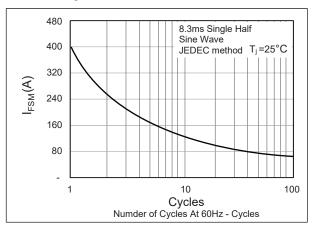
Current Derating



Recovery Charge



Forward Surge Current



CSRI2×50-065P1B

Disclaimer

DACO Semiconductor reserves the right to make modifications, enhancements, improvements, corrections, or other changes to this document and any product described herein without prior notice.

DACO Semiconductor makes no warranty, representation, or guarantee regarding the suitability of its products for any particular purpose, nor does DACO Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any liability, including without limitation special, consequential or incidental damages.

Purchasers are responsible for its products and applications using DACO Semiconductor products, including compliance with all laws, regulations, and safety requirements or standards, regardless of any support or application information provided by DACO Semiconductor. "Typical" parameters that may be provided in DACO Semiconductor datasheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typical" must be validated for each customer application by the customer's technical experts.

DACO Semiconductor products are not designed, authorized, or warranted to be suitable for use in life support, life-critical or safety-critical systems, or equipment, nor in applications where failure or malfunction of DACO Semiconductor's product can reasonably be expected to result in personal injury, death or severe property or environmental damage. DACO Semiconductor accepts no liability for the inclusion and/or use of DACO Semiconductor's products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Purchasers who buy or use DACO Semiconductor products for any unintended or unauthorized applications are required to indemnify and absolve DACO Semiconductor, its suppliers, and distributors from any claims, costs, damages, expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that DACO Semiconductor was negligent regarding the design or manufacture of the part.

No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or by any information storage and retrieval system, or otherwise, without the prior written permission of DACO Semiconductor Co., Ltd.